

N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☒ Advanced trench cell design
- ☒ Low thermal impedance
- ☒ Fast switching speed
- ☒ 100% Avalanche tested

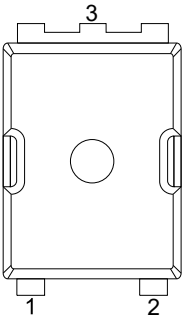
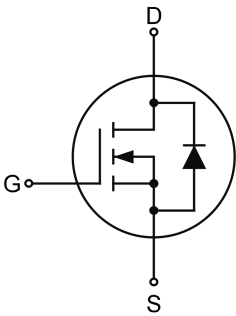
1.2 Applications

- ☒ DC/DC converter
- ☒ Power switch
- ☒ Motor drives

1.3 Quick reference

- ☒ $BV \geq 100\text{ V}$
- ☒ $P_D \leq 166.7\text{ W}$
- ☒ $I_D \leq 120\text{ A}$
- ☒ $R_{DS(ON)} \leq 3.7\text{ m}\Omega @ V_{GS} = 10\text{ V}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Gate(G)	 Top View PTO-252-3L	
2	Source(S)		
3	Drain(D)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	Drain-Source Voltage	$T_C=25^{\circ}\text{C}$	100	-	V
V_{GS}	Gate-Source Voltage	$T_C=25^{\circ}\text{C}$	-	± 20	V
I_D	Continuous Drain Current (Silicon limit)	$T_C=25^{\circ}\text{C}$	-	154	A
I_D	Continuous Drain Current (Package limit)	$T_C=25^{\circ}\text{C}$, $V_{GS}=10\text{ V}$	-	120	A
I_D	Continuous Drain Current	$T_C=100^{\circ}\text{C}$, $V_{GS}=10\text{ V}$	-	94	A
I_{DM}^*	Pulsed Drain Current	$T_C=25^{\circ}\text{C}$, $V_{GS}=10\text{ V}$	-	480	A
P_D	Drain Power Dissipation	$T_C=25^{\circ}\text{C}$	-	166.7	W
E_{AS}	Single Pulsed Avalanche Energy	$V_{DD}=50\text{ V}$, $L=0.3\text{ mH}$	-	811	mJ
T_J, T_{stg}	Operating Junction and Storage Temperature Range		-55	150	$^{\circ}\text{C}$
$R_{\theta JA}$	Thermal Resistance-Junction to Ambient		-	40	$^{\circ}\text{C/W}$
$R_{\theta JC}$	Thermal Resistance-Junction to Case		-	0.8	

Notes:

- * Pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- ** Surface mounted on 1 in^2 pad area, $t \leq 10\text{ sec}$.
- *** Limited by bonding wire.

4. Marking Information

Product Name	Marking
KJ037N10Y	KJ037N10Y XXXXXX-X

5. Ordering Code

Product Name	Package	Reel size	Tape width	Quantity (pcs)
KJ037N10Y	PTO-252-3L	13"	16 mm	3000

Note: KUAJIEXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C)

6. Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0 V, I _{DS} =250 μA	100	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250 μA	2.0	-	4.0	V
I _{DSS}	Drain Leakage Current	V _{DS} =100 V, V _{GS} =0 V	-	-	1	μA
I _{GSS}	Gate Leakage Current	V _{DS} =0 V, V _{GS} =±20 V	-	-	±100	nA
R _{DS(ON)}	On-State Resistance	V _{GS} =10 V, I _{DS} =50 A	-	3.0	3.7	mΩ
g _{FS}	Forward Transconductance	V _{GS} =5 V, I _{DS} =50 A	-	120	-	S
R _g	Gate Resistance	f=1 MHz	-	1.5	-	Ω
Diode Characteristics						
V _{SD}	Diode Forward Voltage	I _{SD} =50 A, V _{GS} =0 V	-	-	1.2	V
t _{rr}	Reverse Recovery Time	V _{DS} =50 V, I _{DS} =50 A, V _{GS} =0 V, dI _{SD} /dt=100 A/μs	-	50	-	ns
Q _{rr}	Reverse Recovery Charge		-	108	-	nC
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{GS} =10 V, V _{DS} =50 V, I _{DS} =50 A, f=1 MHz	-	7066	-	pF
C _{oss}	Output Capacitance		-	918	-	
C _{rss}	Reverse Transfer Capacitance		-	39	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} =50 V, V _{GEN} =10 V, R _G =6 Ω, I _{DS} =50 A	-	59	-	ns
t _r	Turn-on Rise Time		-	72	-	
t _{d(off)}	Turn-off Delay Time		-	88	-	
t _f	Turn-off Fall Time		-	39	-	
Gate Charge Characteristics						
Q _g	Total Gate Charge	V _{DS} =50 V, V _{GS} =10 V, I _{DS} =20 A	-	123	-	nC
Q _{gs}	Gate-Source Charge		-	36	-	
Q _{gd}	Gate-Drain Charge		-	38	-	

7. Typical Characteristics

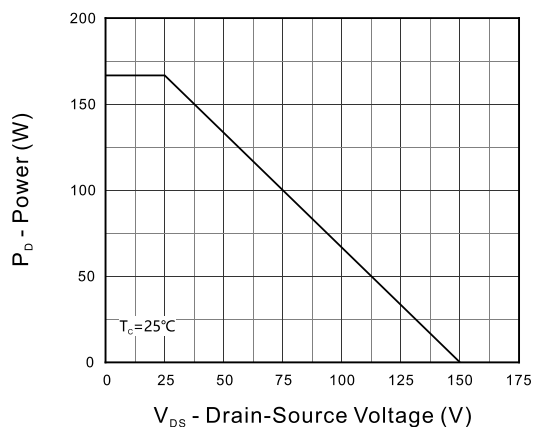


Figure 1. Output Characteristics

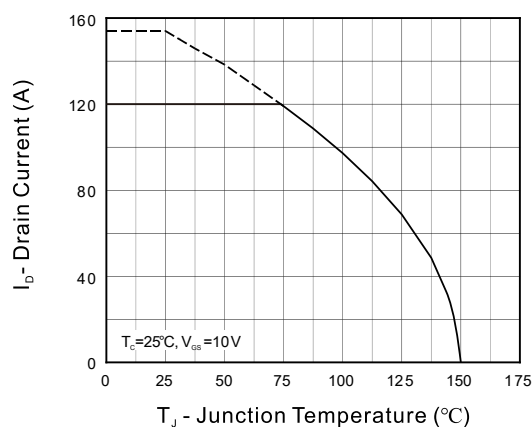


Figure 2. Current Capability

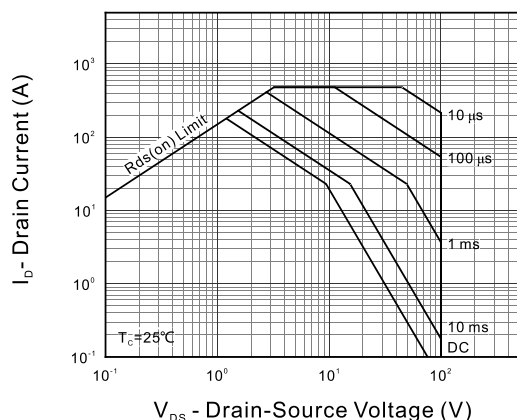


Figure 3. Safe Operation Area

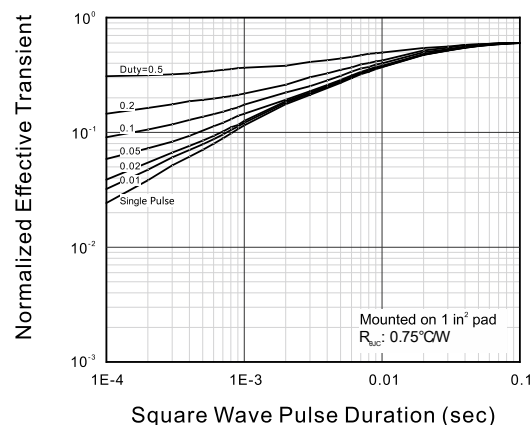


Figure 4. Transient Thermal Impedance

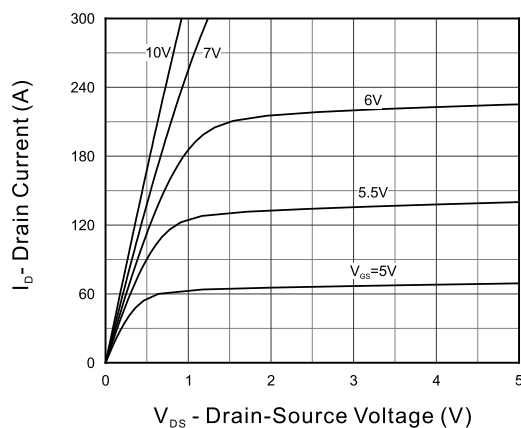


Figure 5. Output Characteristics

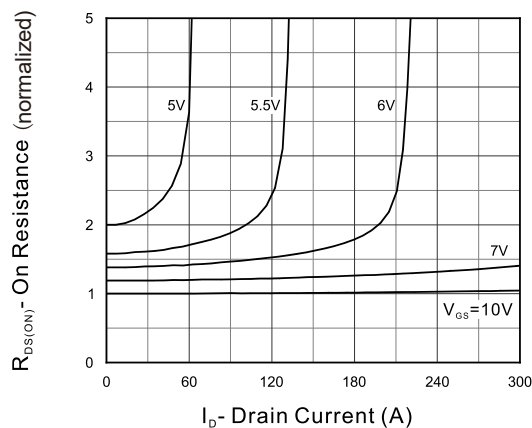
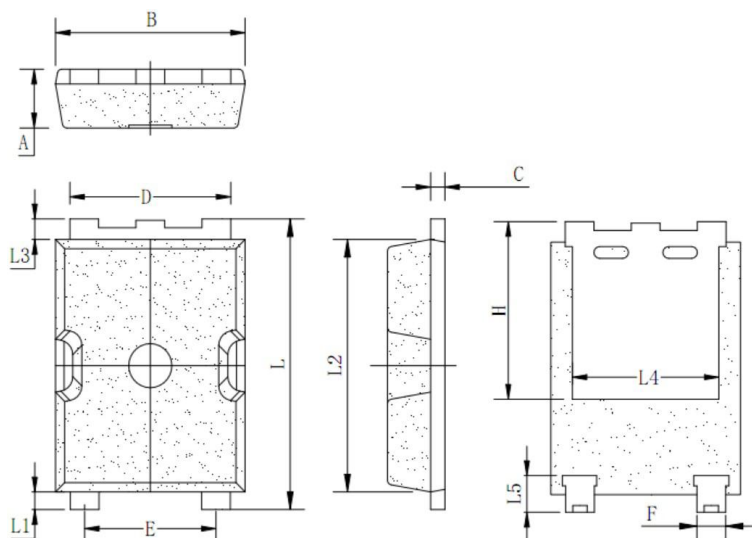


Figure 6. On Resistance

7. Typical Characteristics (cont.)

8. Package Dimensions

PTO-252-3L Package



Symbol	Dimensions In Millimeters	
	MIN	MAX
A	1.95	2.05
B	6.55	6.65
C	0.47	0.55
D	5.50	5.70
E	4.55	4.65
F	0.95	1.05
H	5.90	6.20
L	9.85	9.95
L1	0.55	0.65
L2	8.55	8.65
L3	0.65	0.75
L4	4.65	4.90
L5	1.15	1.35